



## SB520 - SB5100

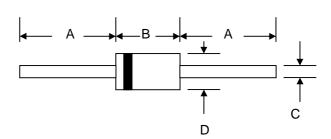




### **5.0A SCHOTTKY BARRIER DIODE**

#### **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications



#### **Mechanical Data**

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per
   New Action 1999
  - MIL-STD-202, Method 208
    Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Lead Free: For RoHS / Lead Free Version,
   Add "-LF" Suffix to Part Number, See Page 4

| DO-201AD             |      |      |  |  |  |  |  |
|----------------------|------|------|--|--|--|--|--|
| Dim                  | Min  | Max  |  |  |  |  |  |
| Α                    | 25.4 | 1    |  |  |  |  |  |
| В                    | 7.20 | 9.50 |  |  |  |  |  |
| С                    | 1.20 | 1.30 |  |  |  |  |  |
| D                    | 4.80 | 5.30 |  |  |  |  |  |
| All Dimensions in mm |      |      |  |  |  |  |  |

### Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic  | Symbol             | SB520       | SB530 | SB540 | SB550 | SB560 | SB580 | SB5100 | Unit |
|---|--------------------|-------------|-------|-------|-------|-------|-------|--------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                                | VRRM<br>VRWM<br>VR | 20          | 30    | 40    | 50    | 60    | 80    | 100    | ٧    |
| RMS Reverse Voltage   | VR(RMS)            | 14          | 21    | 28    | 35    | 42    | 56    | 70     | ٧    |
| Average Rectified Output Current @T <sub>L</sub> = 100°C (Note 1)   | lo                 | 5.0         |       |       |       |       |       |        | Α    |
| Non-Repetitive Peak Forward Surge Current 8.3ms<br>Single half sine-wave superimposed on rated load<br>(JEDEC Method) | IFSM               | 150         |       |       |       |       |       | А      |      |
| Forward Voltage @I <sub>F</sub> = 5.0A  | VFM                | 0.55        |       |       | 0.70  |       | 0.85  |        | ٧    |
|   | lкм                | 0.5<br>50   |       |       |       |       |       | mA     |      |
| Typical Junction Capacitance (Note 2)   | Cj                 | 500         |       |       | 400   |       |       |        | pF   |
| Typical Thermal Resistance (Note 1)   | RθJA               | 10          |       |       |       |       |       | °C/W   |      |
| Operating and Storage Temperature Range   | Tj, Tstg           | -65 to +150 |       |       |       |       |       |        | °C   |

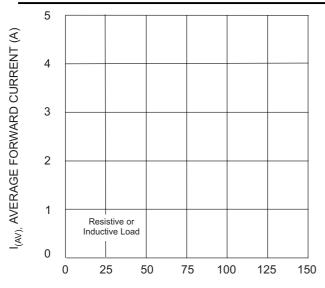
Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.

2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

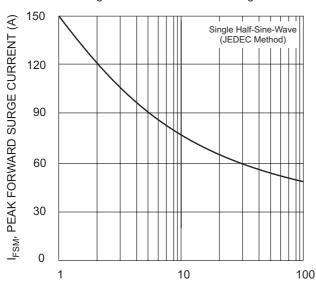




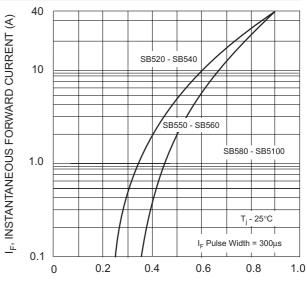
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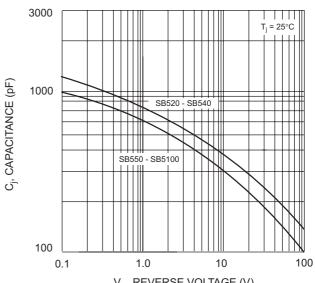
T<sub>L</sub>, LEAD TEMPERATURE (°C) Fig. 1 Forward Current Derating Curve



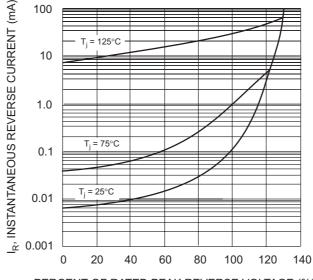
NUMBER OF CYCLES AT 60Hz Fig. 3 Max Non-Repetitive Peak Fwd Surge Current



V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics



V<sub>R</sub>, REVERSE VOLTAGE (V) Fig. 4 Typical Junction Capacitance



PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5 Typical Reverse Characteristics